

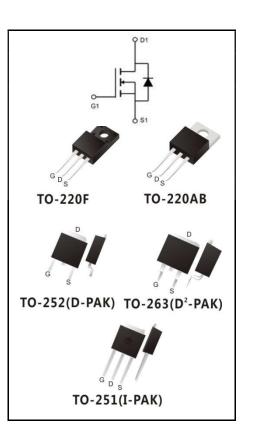
# 500V N-CHANNEL ENHANCEMENT MODE MOSFET

### MAIN CHARACTERISTICS

| I <sub>D</sub>                                | 5A                         |
|---|----------------------------|
| V <sub>DSS</sub>                              | 500V                       |
| R <sub>DSON</sub> -typ(@V <sub>GS</sub> =10V) | <1.5Ω <b>(Type:1.39 Ω)</b> |

#### **Features**

Fast Switching
Low ON Resistance
Low Gate Charge
100% Single Pulse avalanche energy Test
LeadfreeincomplywithEURoHS2011/65/EUdirectives



#### **Mechanical Data**

Case: Molded plastic
Mounting Position: Any
Molded Plastic: UL Flammability Classification Rating 94V-0
Solder bath temperature275°C maximum,10s per JESD22-106

### **Product Specification Classification**

| Part Number | Package        | Marking           | Pack         |
|-------------|----------------|-------------------|--------------|
| YFW5N50AT   | TO-220AB       | YFW 5N50AT XXXXX  | 50PCS/Tube   |
| YFW5N50AF   | TO-220F(0.5mm) | YFW 5N50AF XXXXX  | 50PCS/Tube   |
| YFW5N50AS   | TO-263         | YFW 5N50AS XXXXX  | 50PCS/Tube   |
| YFW5N50AS-R | TO-263         | YFW 5N50AS XXXXX  | 800PCS/Tape  |
| YFW5N50AMJ  | TO-251         | YFW 5N50AMJ XXXXX | 80PCS/Tube   |
| YFW5N50AD   | TO-252         | YFW 5N50AD XXXXX  | 2500PCS/Tape |

# YFW5N50AT/AF/AS/AMJ/AD



# YFW5N50AT/AF/AS/AMJ/AD

## Maximum Ratings at Tc=25°C unless otherwise specified

| <u>Okenne staristica</u>                | Cumph ala       | Value       |      |         | 11    |   |
|---|-----------------|-------------|------|---------|-------|---|
| Characteristics                         | Symbols         | 220AB/263   | 220F | 251/252 | Units |   |
| Drain-Source Voltage                    | V <sub>DS</sub> | 500         |      |         | v     |   |
| Gate-Source Voltage                     | V <sub>GS</sub> | ±30         |      |         | v     |   |
| Continue Drain Current                  |                 | 5           |      |         |       | • |
| - Continuous(Tc=100°C)                  | D               | 3.1         |      |         | Α     |   |
| Pulsed Drain Current (Note1)            | Ырм             | 20          |      |         | Α     |   |
| Power Dissipation                       | <b>P</b> ⊳      | 75          | 33   | 63      | w     |   |
| -Derate above 25°C                      | PD              | 0.56        | 0.33 | 0.62    | W/°C  |   |
| Single Pulse Avalanche Energy (Note2)   | Eas             | 195         |      | mJ      |       |   |
| Avalanche Current (Note 1)              | lar             | 5           |      | Α       |       |   |
| Repetitive Avalanche Energy (Note 1)    | Ear             | 10.1        |      | mJ      |       |   |
| Operating Temperature Range             | TJ              | 150         |      | °C      |       |   |
| Storage Temperature Range               | Тѕтс            | -55 to +150 |      | °C      |       |   |
| Thermal Resistance, Junction to Case    | Rejc            | 1.65        | 3.46 | 2.25    | °C/W  |   |
| Thermal Resistance, Junction to Ambient | Reja            | 62.5        | 62.5 | 62.5    | °C/W  |   |

## Maximum Ratings at Tc=25°C unless otherwise specified

| Characteristics                  | Test Condition   | Symbols             | Min | Тур  | Max  | Units |
|----------------------------------|--|---------------------|-----|------|------|-------|
| Drain-Source Breakdown Voltage   | V <sub>GS</sub> = 0 V,I <sub>D</sub> = 250 μA                                    | BV <sub>DSS</sub>   | 500 | -    | -    | v     |
| Drain-Source Leakage Current     | V <sub>DS</sub> = 500 V, V <sub>GS</sub> = 0 V                                   |                     | -   | -    | 1    | uA    |
|                                  | V <sub>DS</sub> =400V,Tc=125°C   | DSS                 | -   | -    | 10   |       |
| Gate Leakage Current             | $V_{GS}$ = ± 30 V, VDS = 0 V   | I <sub>GSS</sub>    | -   | -    | ±100 | nA    |
| Gate-Source Threshold Voltage    | $V_{DS}$ = $V_{GS}$ , $I_D$ = 250 $\mu$ A  | V <sub>GS(th)</sub> | 2   | -    | 4    | v     |
| Drain-Source On-State Resistance | V <sub>GS</sub> = 10 V, I <sub>D</sub> = 2.5 A                                   | R <sub>DS(on)</sub> | -   | 1.39 | 1.5  | Ω     |
| Forward Transconductance         | V <sub>DS</sub> = 15 V, I <sub>D</sub> = 2.5A                                    | gfs                 | -   | 4    | -    | S     |
| Input Capacitance                |  | C <sub>iss</sub>    | -   | 545  | -    |       |
| Output Capacitance               | $V_{GS} = 0 V, V_{DS} = 25 V, f = 1MHz$  | C <sub>oss</sub>    | -   | 63   | -    | рF    |
| Reverse Transfer Capacitance     |  | C <sub>rss</sub>    | -   | 5.5  | -    | 1     |
| Turn-on Delay Time               |  | td(ON)              | -   | 9    | -    |       |
| Rise Time                        | I <sub>D</sub> =5 A, V <sub>DD</sub> =250 V,                                     | tr                  | -   | 11   | -    |       |
| Turn-Off Delay Time              | R <sub>G</sub> = 10 Ω(Note3.4)   | td(OFF)             | -   | 29   | -    | - nS  |
| Fall Time                        |  | tf                  | -   | 16   | -    | 1     |
| Total Gate Charge                |  | Q <sub>G</sub>      | -   | 14.5 | -    |       |
| Gate to Source Charge            | I <sub>D</sub> = 5A, V <sub>DD</sub> = 400 V,<br>V <sub>GS</sub> = 10 V(Note3.4) | Q <sub>GS</sub>     | -   | 3.5  | -    | nC    |
| Gate to Drain Charge             |  | $\mathbf{Q}_{GD}$   | -   | 7    | -    |       |



# YFW5N50AT/AF/AS/AMJ/AD

### Source-Drain Diode Characteristics at Ta=25°C unless otherwise specified

| Characteristics                          | Test Condition  | Symbols         | Min | Тур | Max | Units |
|--|---|-----------------|-----|-----|-----|-------|
| Maximun Body-Diode Continuous Current    |   | ls              | -   | -   | 5   | A     |
| Maximun Body-Diode Pulsed Current(Note2) |   | I <sub>SM</sub> | -   | -   | 20  | A     |
| Drain-Source Diode Forward Voltage       | I <sub>SD</sub> = 5 A   | V <sub>SD</sub> | -   | -   | 1.4 | v     |
| Reverse Recovery Time                    | I <sub>SD</sub> =5 A, V <sub>GS</sub> = 0 V,<br>dI <sub>F</sub> / dt = 100 A/µs | trr             | -   | 391 | -   | nS    |
| Reverse Recovery Charge                  | α <sub>F</sub> / αι – 100 Α/μs  | Qrr             | -   | 1.7 | -   | uC    |

Note:

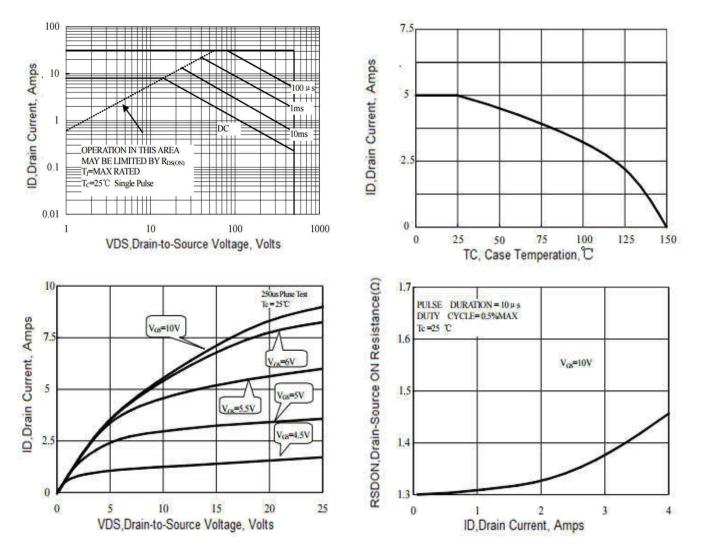
1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. IAS = 5 A, VDD = 50 V, L =16mH, RG = 25Ω, starting TJ = 25°C.

3. ulse test: Pulse Width  $\leq$  300 µ s, Duty Cycle $\leq$  2%.

4. Essentially Independent of Operating Temperature.

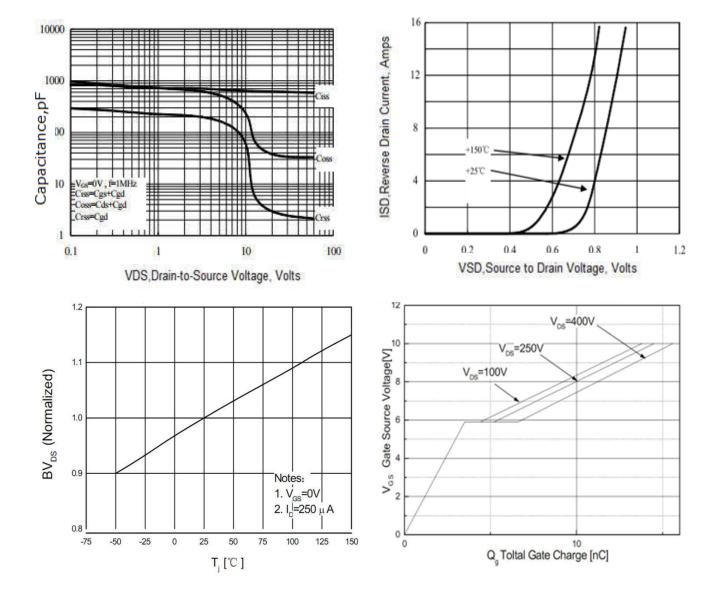
### **Ratings and Characteristic Curves**





# YFW5N50AT/AF/AS/AMJ/AD

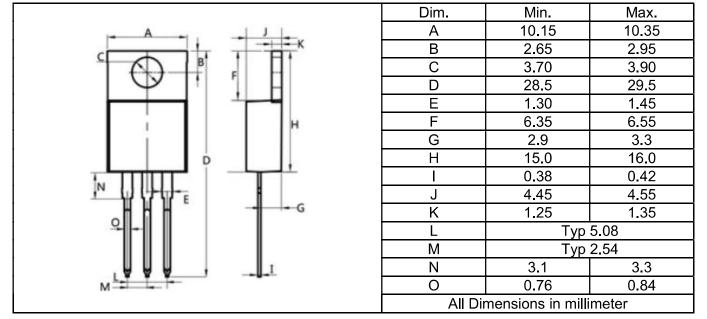
### **Ratings and Characteristic Curves**



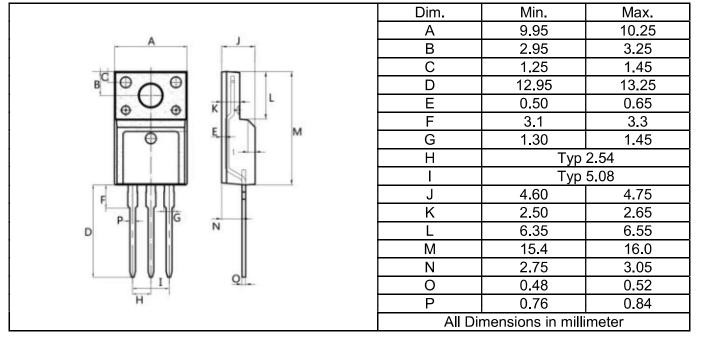


### **Package Outline Dimensions Millimeters**

### **TO-220AB**



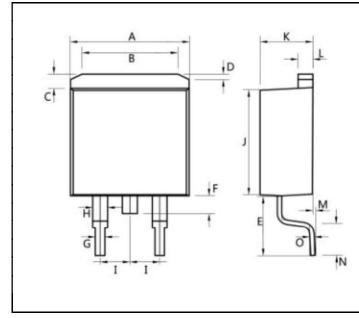
### TO-220F





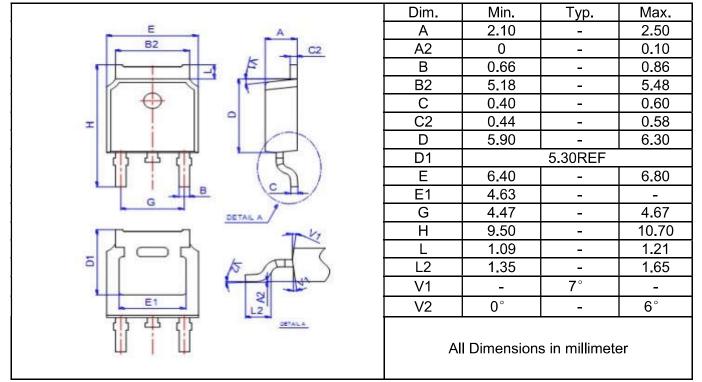
### Package Outline Dimensions Millimeters

### TO-263



| Dim.                         | Min.    | Max. |  |  |
|------------------------------|---------|------|--|--|
| A                            | 10.1    | 10.2 |  |  |
| В                            | 7.4     | 7.6  |  |  |
| С                            | 1.3     | 1.5  |  |  |
| D                            | 0.55    | 0.75 |  |  |
| E                            | 5.0     | 6.0  |  |  |
| F                            | 1.4     | 1.6  |  |  |
| G                            | 0.78    | 0.86 |  |  |
| Н                            | 1.2     | 1.3  |  |  |
|                              | Typ2.54 |      |  |  |
| J                            | 8.4     | 8.6  |  |  |
| K                            | 4.45    | 4.55 |  |  |
| L                            | 1.25    | 1.35 |  |  |
| М                            | 0.02    | 0.1  |  |  |
| N                            | 2.4     | 2.8  |  |  |
| 0                            | 0.36    | 0.40 |  |  |
| All Dimensions in millimeter |         |      |  |  |

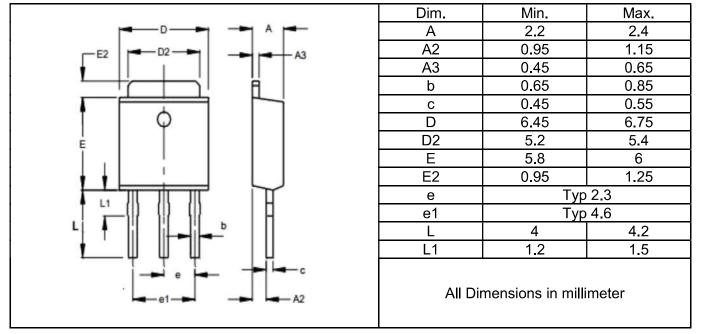
### TO-252





### Package Outline Dimensions Millimeters

### TO-251



单击下面可查看定价,库存,交付和生命周期等信息

>>YFW(佑风微)